

PH922DBR 922nm Series

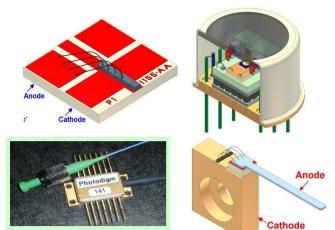
High-Power Single-Frequency Laser Diode

Technology

- DBR Single-Frequency Laser Chip
- InGaAs QW Active Layer
- Epi designed for high reliability

Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



Description

The PH922DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Applications include spectroscopy, difference frequency generation, and low power DPSS replacement.

Absolute Maximum Ratings

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T _{STG}	°C	0	80
Operating Temperature	T_OP	°C	5.0	70
CW Laser Forward Current, T=T _{op}	I _F	mA	-	150**
Pulsed Laser Forward Current, T=25°C,	I _F	А	-	0.5
PW=300 ns, DC=10%				
Laser Reverse Voltage	V_R	V	-	2.0
Photodiode Forward Current 1/2/	I_{P}	mA	-	5.0
Photodiode Reverse Voltage 1/2/	V_R	V	-	20.0
Photodiode Dark Current, V _R =10V, LD I _F =0, 1/2/	I_{D}	nA	-	50
TEC Current 1/2/	I _{TEC}	Α	-1.8	1.8
TEC Voltage 1/2/	V_{TEC}	V	-1.9	1.9
Thermistor Current 1/2/	I _{THRM}	mA	-	1.0
Thermistor Voltage 1/2/	V_{THRM}	V	-	10
ESD (HBM)	-	V	-	500
External Back Reflection	-	dB	-	-14
Lead Soldering Temperature, 10 sec. Max., 1/2/	-	°C	-	260
Fiber Pull Force 1/	-	N		5.0
Fiber Bend Radius 1/	-	mm	-	35

^{1/} Butterfly package 2/ TO-8 package **Do not exceed drive current or operating power of supplied LIV**



CW Characteristics at $T_C = 25$ °C unless otherwise specified

Parameter	Symbol	Unit	Min	Тур	Max
Center Wavelength	λς	nm	920	922	924
Optical Output Power @ LIV current	Ро	mW	See Power Options Call-out		
Slope Efficiency, 1/	ηd	W/A	0.3	0.36	
Slope Efficiency	ηd	W/A	0.6	0.72	-
Threshold Current	lth	mA	ı	30	40
Laser Series Resistance	R_s	Ω	ı	2.0	2.5
Laser Forward Voltage	V_{F}	V	-	2.0	2.5
Thermistor Resistance @ 25°C, 1/2/	R_T	ΚΩ	-	10	-
Photodiode Dark Current, V _R =10V, LD I _F =0, 1/2/	I_{D}	nA	ı	-	50
Laser Line Width	Δv	MHz	-	1	-
Beam Divergence @ FWHM	θιι Χ θ⊥	0	-	6 X 32	8 X 34
Side Mode Suppression Ratio	SMSR	dB	-30	-	-
Polarization Extinction Ratio, 1/	PER	dB	-16	-19	-
Laser Polarization				TE	
Mode Structure			Fundamental Mode		

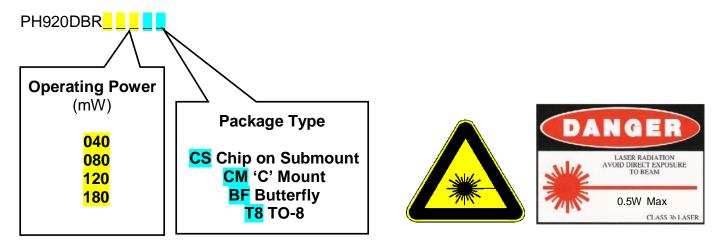
^{1/} Butterfly package 2/ TO-8 package

Handling Precautions

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

How To Order

Part number example: PH922DBR080CM. Assign optical power from those available shown below. Use a three-digit format for all power entries. Call factory for special frequency selection and certification to certain atomic absorption lines. Butterfly package is offered at 50% of output powers shown.



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